

Description

The MOSFET provide the best combination of fast switching, low on-resistance and cost-effectiveness.

MOSFET Product Summary

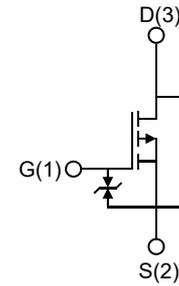
$V_{DS}(V)$	$R_{DS(on)}(\Omega)$	$I_D(mA)$
-30	0.48@ $V_{GS} = -10V$	-200
	0.68@ $V_{GS} = -4.5V$	
	0.75@ $V_{GS} = -4V$	

Feature

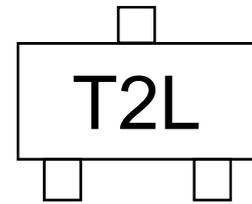
- Low On-resistance.
- Low Gate Threshold Voltage
- Fast Switching Speed
- Small Surface Mount Package
- ESD Protected Gate

Applications

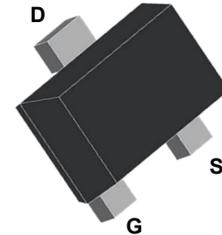
- Switching
- Power Management Functions



Schematic diagram



Marking (Top View)



SOT-723 (Top View)

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 10	V
Drain Current-Continuous	I_D	-200	mA
Pulsed Drain Current	$I_{DP}^{(1)}$	-400	mA
Maximum Power Dissipation	$P_D^{(2)}$	150	mW
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	°C
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}^{(2)}$	833	°C/W

Notes:

1. $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$
2. Each terminal mounted on a recommended land

Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0V, I_D = -1.0mA$	-30	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -30V, V_{GS} = 0V$	-	-	-1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 10V, V_{DS} = 0V$	-	-	± 10	μA
On Characteristics						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -1.0mA$	-0.5	-	-1.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -200mA$	-	0.48	1.0	Ω
		$V_{GS} = -4.5V, I_D = -150mA$	-	0.68	1.2	
		$V_{GS} = -4V, I_D = -150mA$	-	0.75	1.5	
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS} = -10V, I_D = -150mA$	0.2	-	-	s
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS} = -10V, V_{GS} = 0V,$ $f = 1.0MHz$	-	66	-	pF
Output Capacitance	C_{oss}		-	17	-	pF
Reverse Transfer Capacitance	C_{rss}		-	10	-	pF
Switching Characteristics						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = -15V, I_D = 0.15A,$ $V_{GS} = -10V, R_L = 100\Omega,$ $R_G = 10\Omega$	-	3.9	-	ns
Turn-on Rise Time	t_r		-	1.9	-	ns
Turn-Off Delay Time	$t_{d(off)}$		-	12	-	ns
Turn-Off Fall Time	t_f		-	3.2	-	ns
Total Gate Charge	Q_g	$V_{DS} = -15V, I_D = -0.25A,$ $V_{GS} = 10V$	-	1.4	-	nC
Gate-Source Charge	Q_{gs}		-	0.1	-	nC
Gate-Drain Charge	Q_{gd}		-	0.2	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = -0.2A$	-	-	-1.2	V

Typical Characteristics

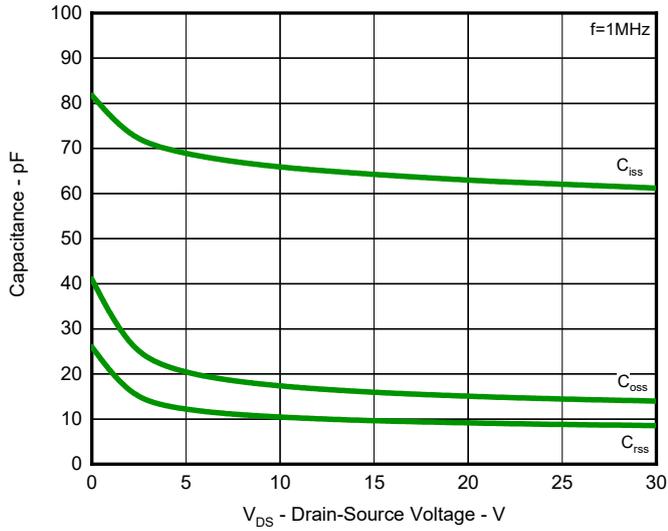


Fig.1 Capacitance vs. Drain-Source Voltage

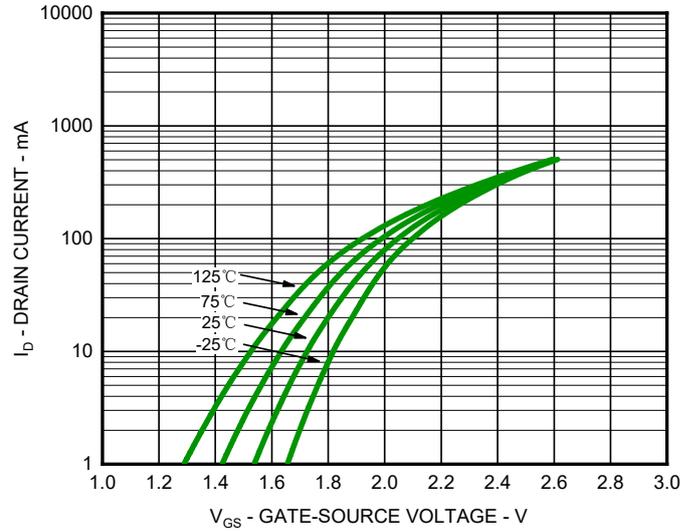


Fig.2 Typical Transfer Characteristics

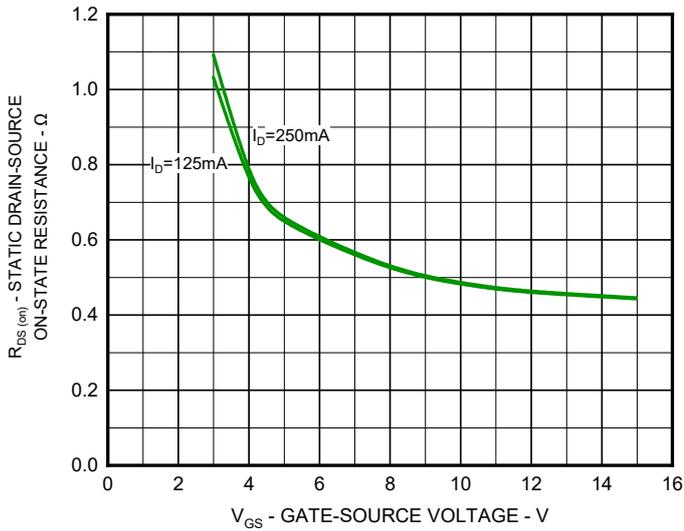


Fig.3 $R_{DS(on)}$ vs. V_{GS}

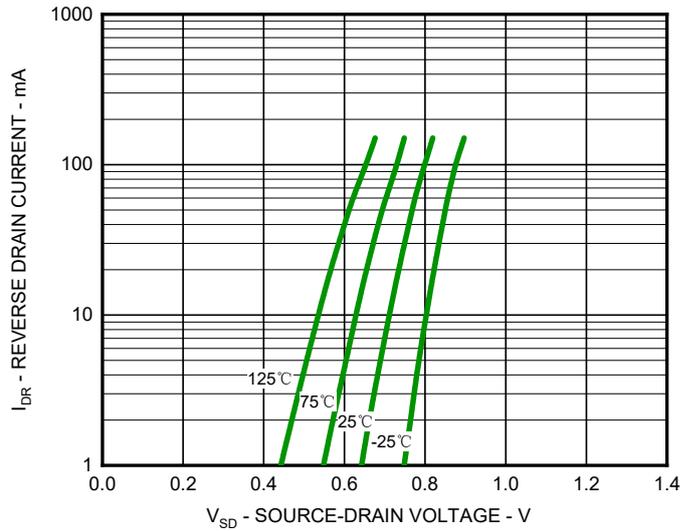


Fig.4 Reverse Drain Current vs. Source-Drain Voltage

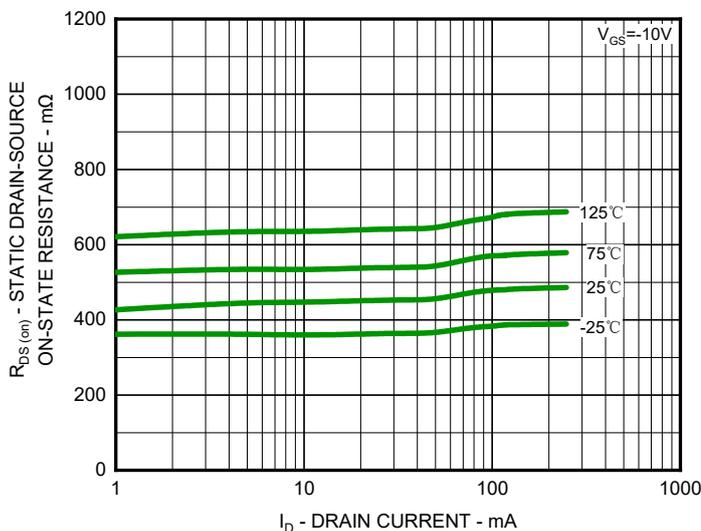


Fig.5 $R_{DS(on)}$ vs. I_D (I)

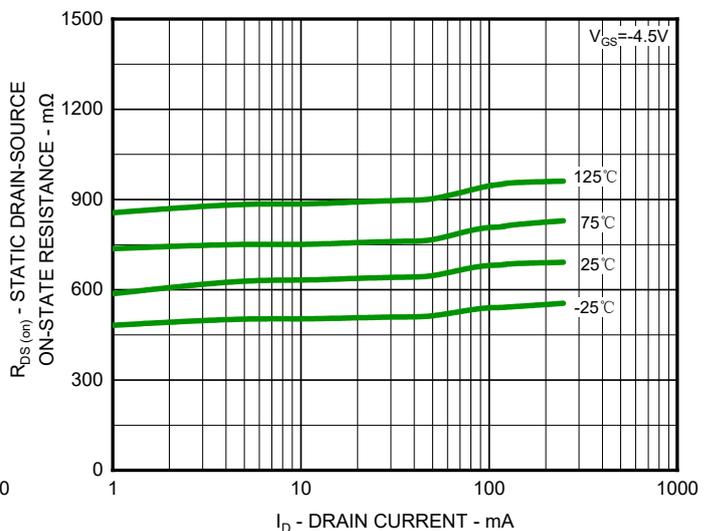


Fig.6 $R_{DS(on)}$ vs. I_D (II)

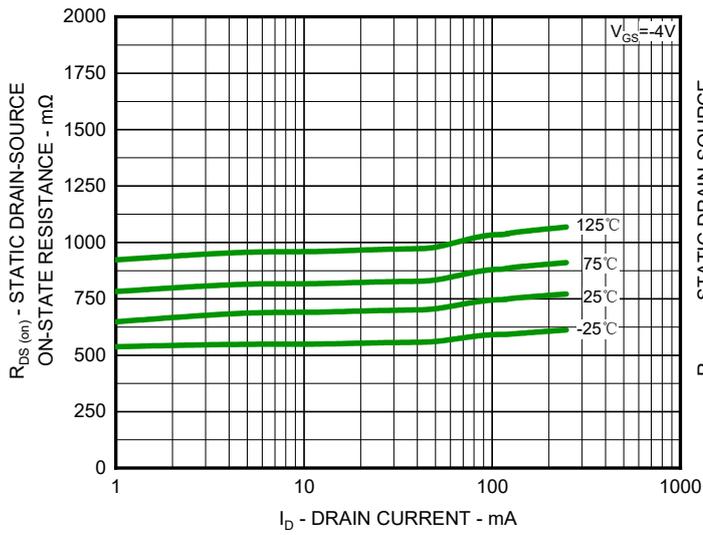


Fig.7 $R_{DS(ON)}$ vs. I_D (III)

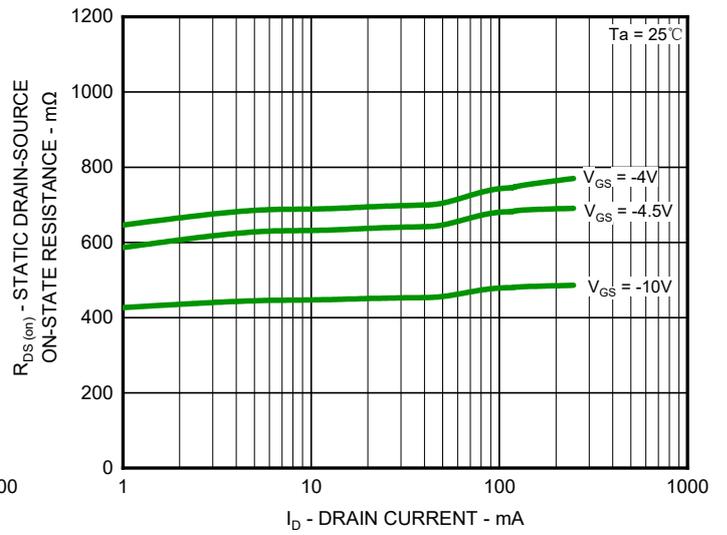
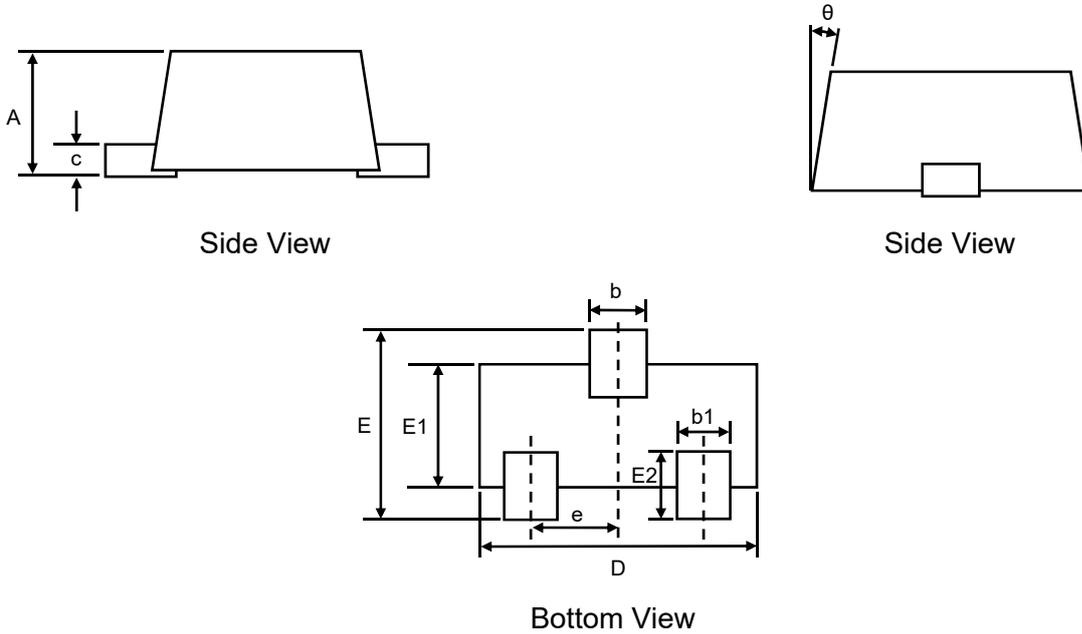
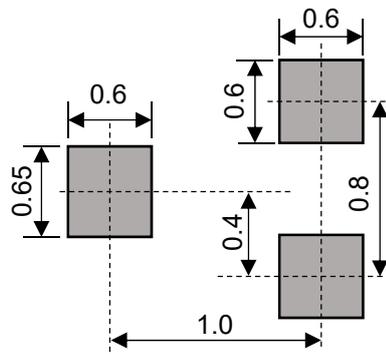


Fig.8 $R_{DS(ON)}$ vs. I_D (IV)

Product dimension (SOT-723)



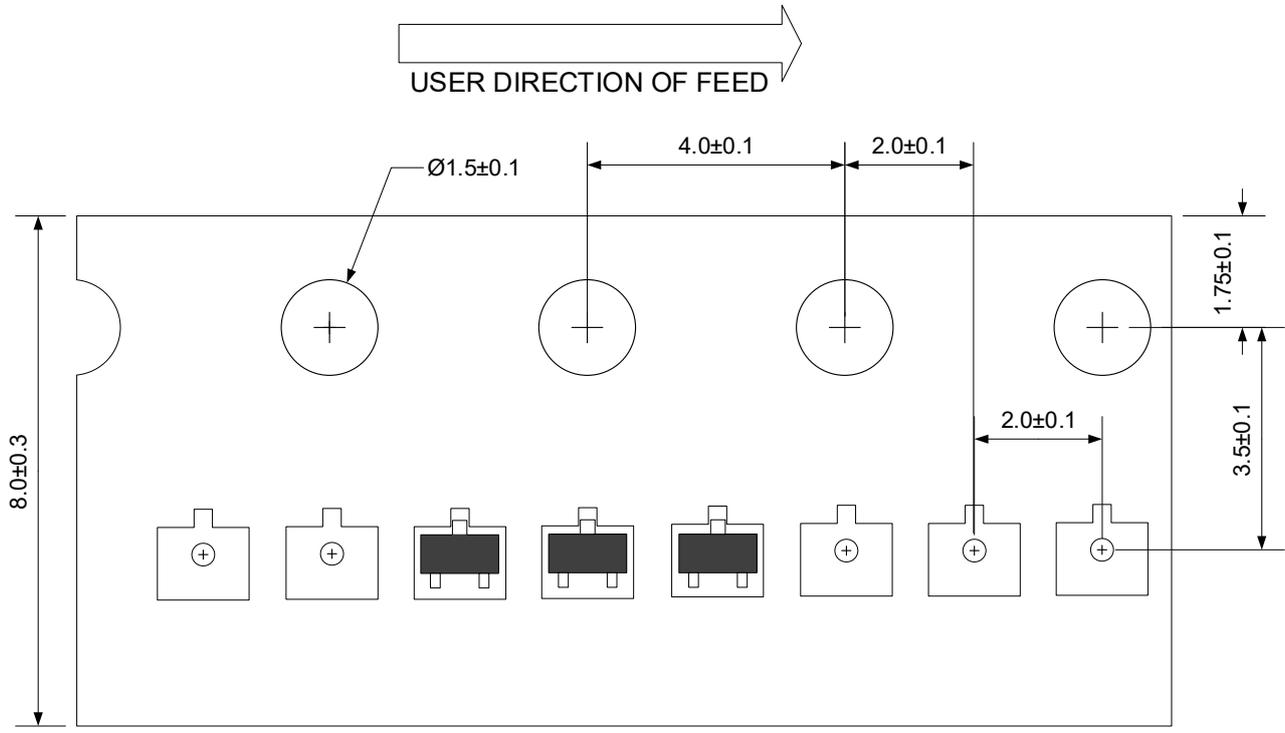
Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	0.42	0.45	0.017	0.018
b	0.20	0.37	0.008	0.015
b1	0.15	0.27	0.006	0.011
c	0.06	0.15	0.002	0.006
D	1.10	1.30	0.043	0.051
E	1.15	1.25	0.045	0.049
E1	0.75	0.85	0.030	0.033
E2	0.20	0.30	0.008	0.012
e	0.40 Ref.		0.016 Ref.	
θ	9°		9°	



Unit:mm

Suggested PCB Layout

Load with information



Unit:mm

Ordering information

Device	Package	Reel	Shipping
PPM723T30V02E	SOT-723 (Pb-Free)	7"	10000 / Tape & Reel

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